	Hits	Search Text	DBs
16	4	(IC or (integrat$4 near9 circuit$4)) and non$4volatile and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
17	0	(IC or (integrat$4 near9 circuit$4)) and $4volatile and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal same (photoresist or resist) same (etch$4 or RIE))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
18	2	(IC or (integrat$4 near9 circuit$4)) and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal same (photoresist or resist) same (etch$4 or RIE))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB